

UFO Doctor, April 18th, 2015, rev. May 22th, 2015

1. Introduction

The Class E Amplifier, invented by Nathan Sokal in 1975, is a tricky RF-circuit and cannot explained here in detail. Please look at the many references in Google to this topic!

In short, a LC-circuit is loaded and short-circuited by a FET at 50% Duty Cycle. The efficiency is near 90%, if low-loss inductors and the appropriate nFET for a distinct frequency are selected!

2. Simulations

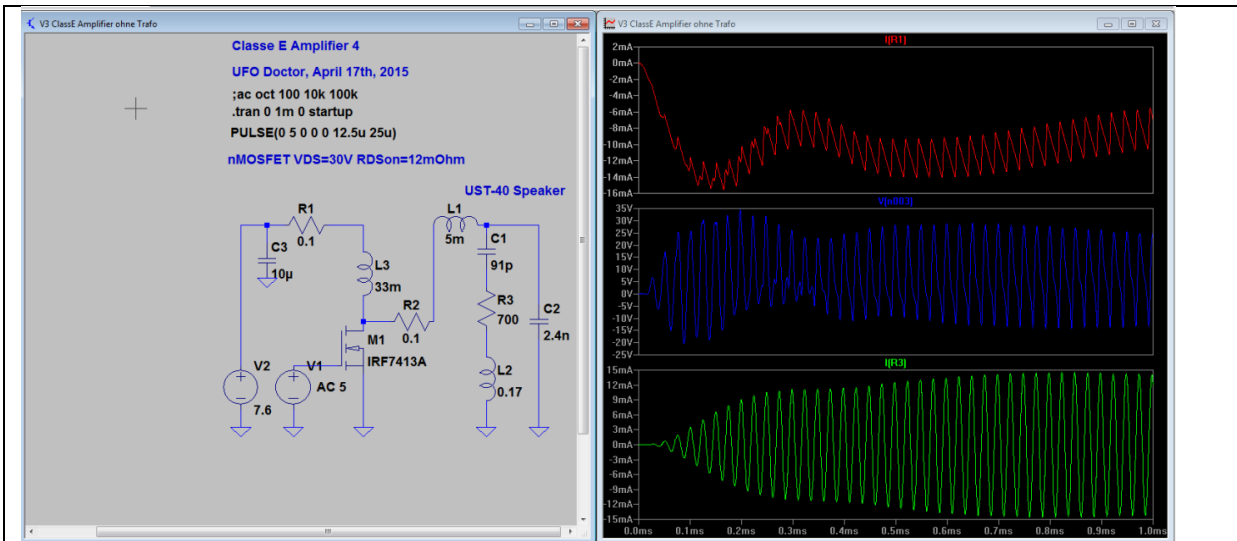


Fig. 1: Transient Analysis, Value of L1 IS VERY CRITICAL!
 Only 10mA Input Current, Output about 35Vpp, WARNINGS: Start-up needs about 0.5msec!

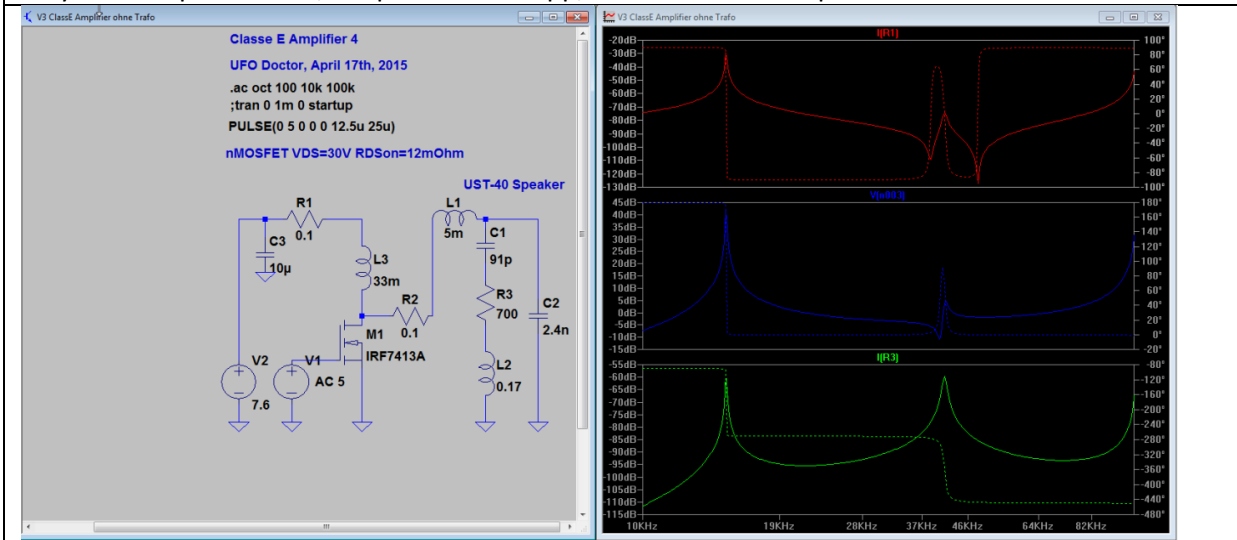


Fig.2: AC-Analysis, Resonanc shifted to about 41kHz
 Internal circuit of the US speaker UST 40 see: <http://www.midnightscience.com/ultrasonics.html>

3. Inductors:

(In general: Self-resonance > operation frequency, low loss)

Type	L mH	RDC Ohm	Comment
Distrelec 33 12 88	33	130	Not good for this job
Ferrite Epcos	6.8	12	Ok for this job!

4. Experiments

4.1. Preliminary Experiment

Supply 7.4V, 1 Ohm Shunt in GND line for supply current monitoring

nMOSFET	L3 mH	L1 mH	Average DC mA	Out Vpp
BSH1052.215	6.8	6.8	16	89

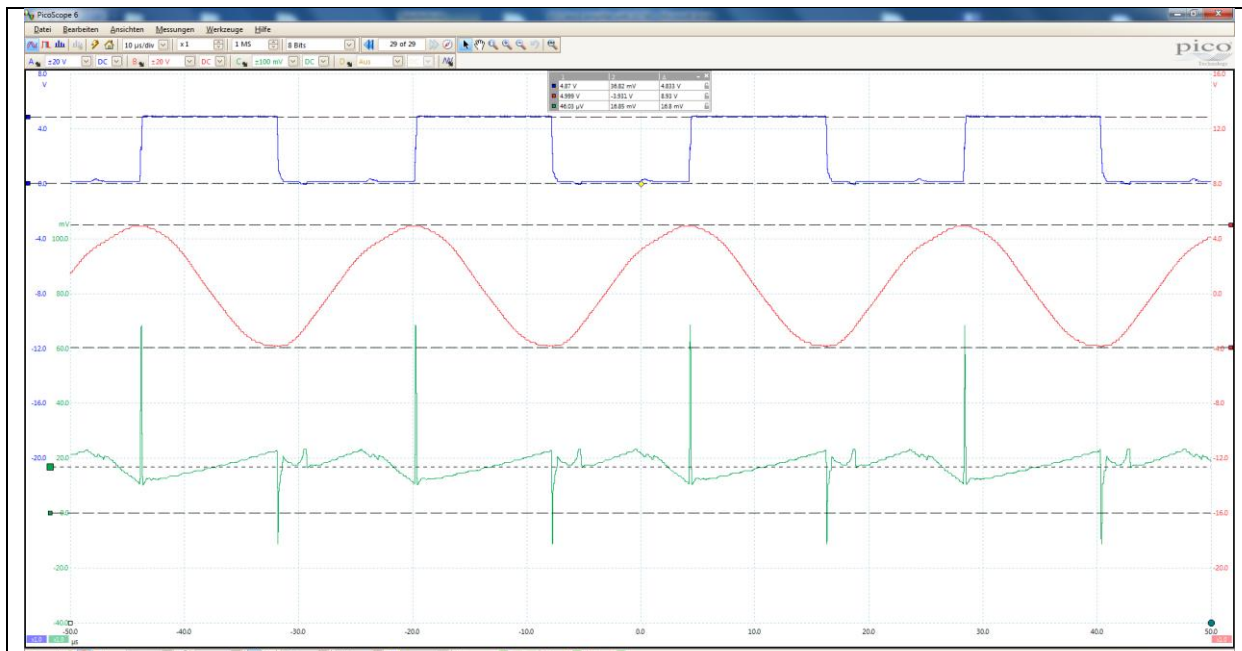


Fig.3: Experimental Data, Time Scale 20usec/Div, LP 5MHz, Maximum at 41.6kHz

Top A: Gate, +/-20V, 4.9V

Middle B: Voltage at UST+/-20V, **Probe 10x1**, 89Vpp

Bottom C: Voltage at 10Ohm Shunt in GND Line, +/-100mV, 16mV=16mA

Comment:

- The maximum amplitude appears not at 40kHz, but at about 41.5kHz. Please ask me not why!

4.2 Experiments with various nMOSFETs

nMOSFET	L3 mH	L1 mH	Average DC mA	Out Vpp
BS898	2x6.8 Serial	6.8	9	81
BS170	2x6.8 Serial	6.8	6	70
BS170	1x6.8	6.8	7	77
BS295	1x6.8	6.8	8	83
BSH1052.215	1x6.8	6.8	14	96

Table 1: Data with various nMOSFETs, Supply 7.4V

Comment:

At this very low frequency of 40kHz almost any nFET or nMOSFET can be applied!

5. Comparison with standard +/-5V UST Drive and Class E Amplifier

5.1. With +/-5V at UST Speaker

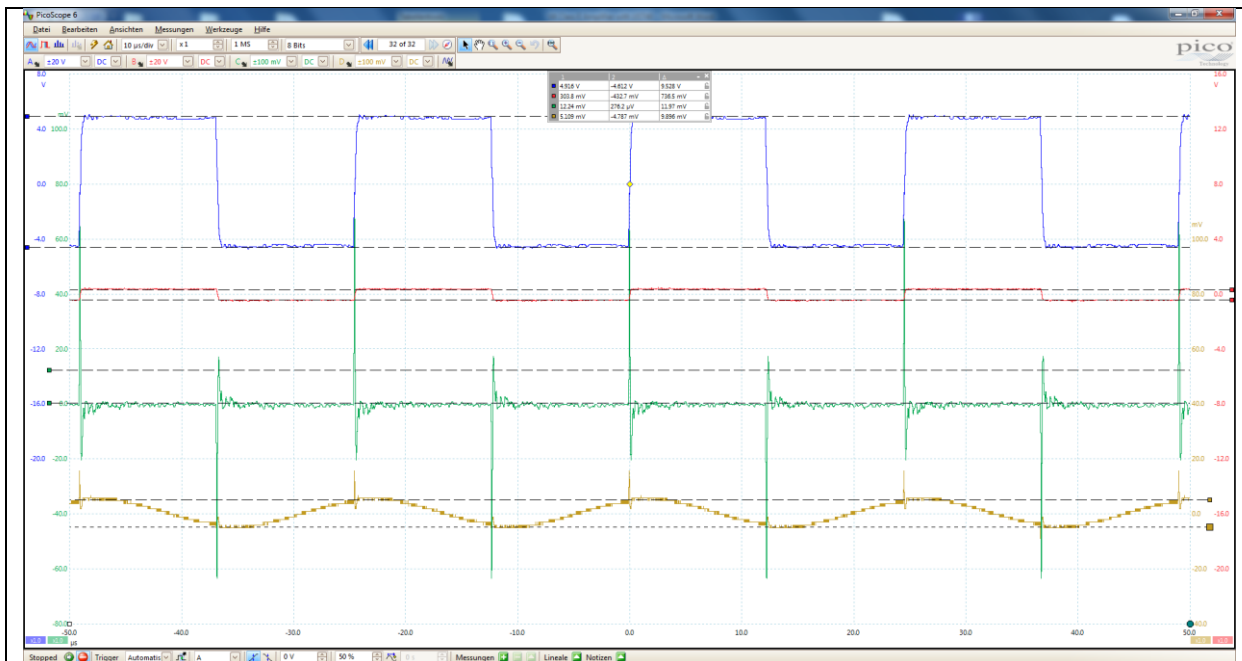


Fig .4: Experimental Data, Time Scale 20usec/Div, LP 5MHz, Maximum at 41.6kHz

Top A: Supply UST, +/-20V, about 10Vpp

Middle B: Voltage at UST,+/-20V, **Probe 10x1**, 7.5Vpp (why not 10Vpp?)

Below C: Voltage at 10Ohm Shunt in GND Line, +/-100mV, not activated

Bottom D: Received US Signal, distance 0.3m, not inline, +/-100mV: 9.8mV

5.2 With 5V Supply at Class E Amplifier

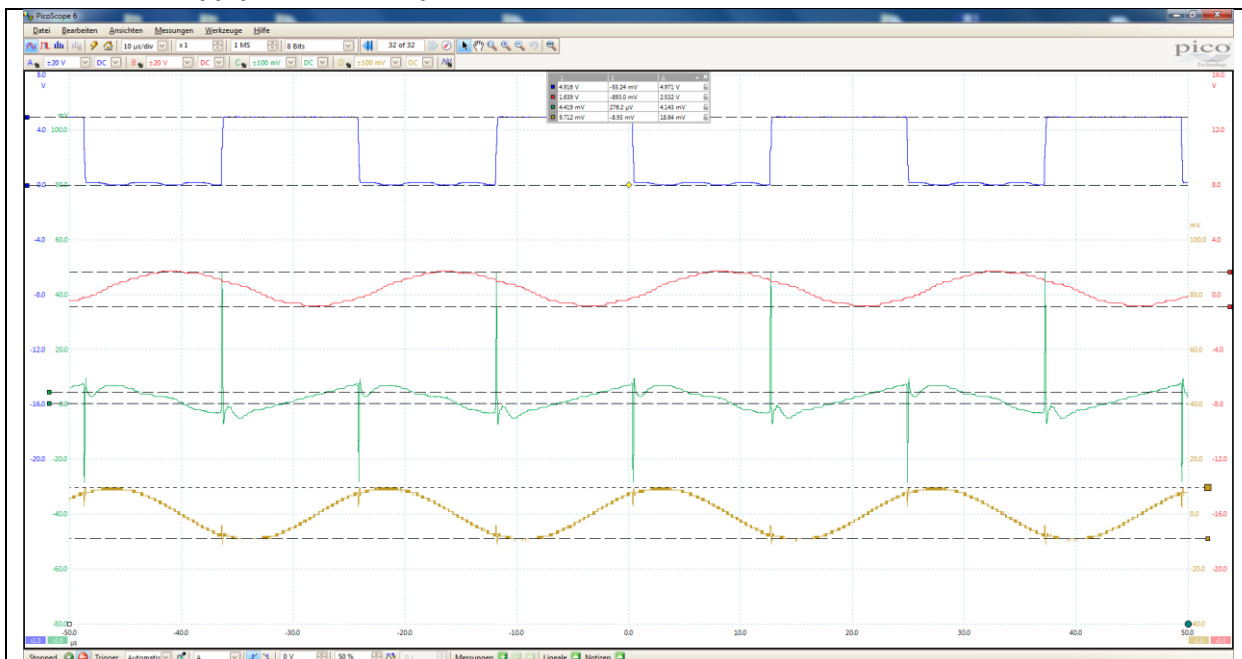


Fig 5: Experimental Data, Time Scale 20usec/Div, LP 5MHz, Maximum at 41.6kHz

Top A: Gate, +/-20V, 0 to 5V

Middle B: Voltage at UST,+/-20V, **Probe 10x1**, 25Vpp

Below C: Voltage at 10Ohm Shunt in GND Line 4.3mV= 4.3mA

Bottom D: Received US Signal, distance 0.3m, not inline, +/-100mV: 18.64mV

5.2. Class E-Amplifier with 7.4V Supply:

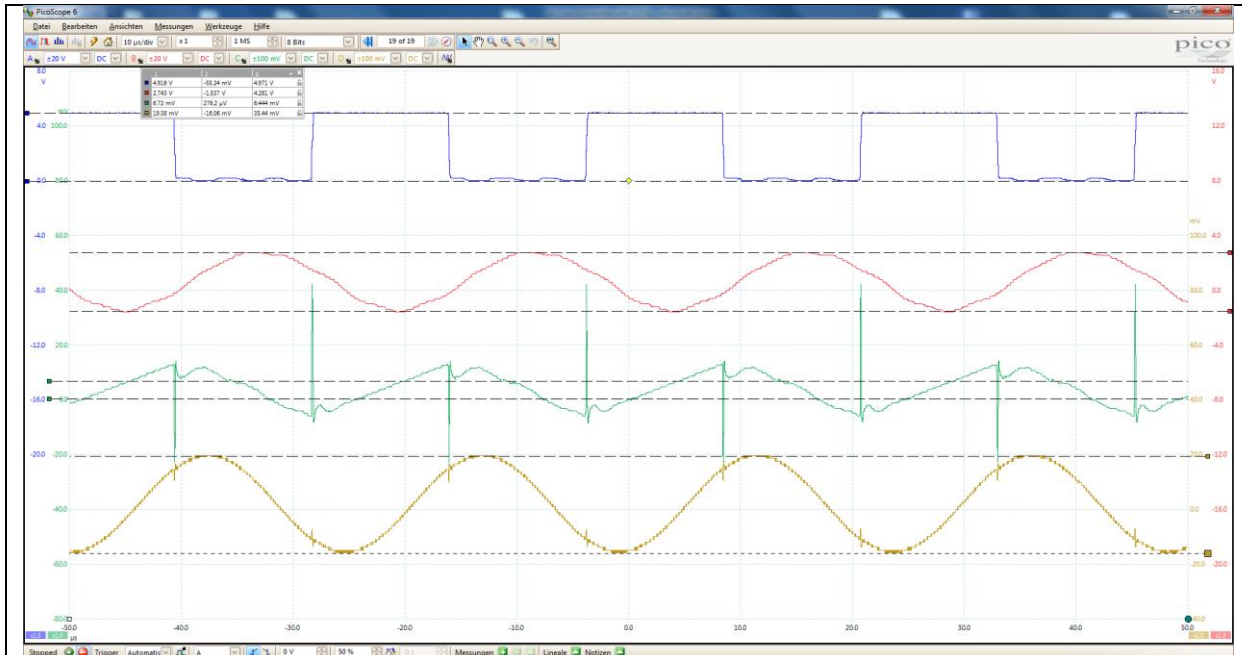


Fig. 6: Experimental Data, Time Scale 20usec/Div, LP 5MHz, Maximum at 41.6kHz

Top A: Gate, +/-20V, 0 to 5V

Middle B: Voltage at UST+/-20V, **Probe 10x1**, 42Vpp (about 15VRMS, below specified 20VRMS, ok)

Below C: Voltage at 10Ohm Shunt in GND Line 6.4mV= 6.4mA

Bottom D: Received US Signal, distance 0.3m, not inline, +/-100mV: 35. 4mV

6. US Supply vs. received US-Signal

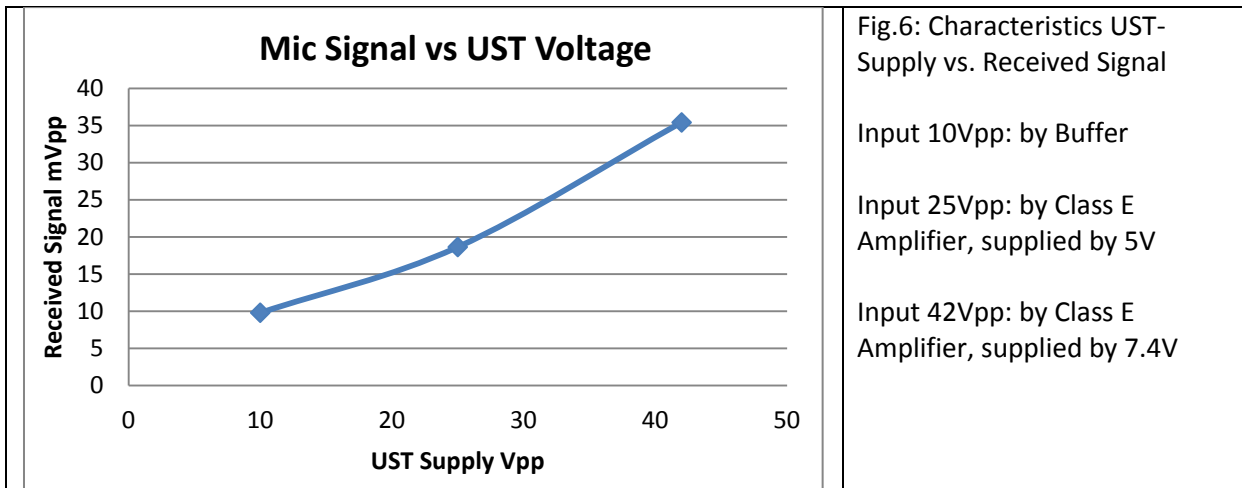


Fig.6: Characteristics UST-Supply vs. Received Signal

Input 10Vpp: by Buffer

Input 25Vpp: by Class E Amplifier, supplied by 5V

Input 42Vpp: by Class E Amplifier, supplied by 7.4V

Comments:

- 10Vpp out of a 5V Supply can be realized by a two Inverting/Noninverting Buffers.
- 20Vpp out of a 5V Supply can be realized by a voltage Doppler, but it consumes about 5mA all the time, also if the US-Speaker is not activated.
- 42Vpp out of a 7.4V Supply can be realized by the tricky Class E-Amplifier. It consumes 16mA, but only if running!
- 42Vpp means 15Vrms, which is < 20Vrms (maximum spec for UST-40)

WARNINGS: During start-up, the output is not stable within the first 0.5msec!